



General Description

The SN74HC/HCT190 are asynchronously presettable up/down BCD decade counters. They contain four master/slave flip-flops with internal gating and steering logic to provide asynchronous preset and synchronous count-up and count-down operation.

Asynchronous parallel load capability permits the counter to be preset to any desired number. Information present on the parallel data inputs (D0 to D3) is loaded into the counter and appears on the outputs when

the parallel load (PL) input is LOW. As indicated in the function table, this operation overrides the counting function.

Counting is inhibited by a HIGH level on the count enable (\bar{CE}) input. When \bar{CE} is LOW internal state changes are initiated synchronously by the LOW-to-HIGH transition of the clock input. The up/down (\bar{U}/D) input signal determines the direction of counting as indicated in the function table. The \bar{CE} input may go LOW when the clock is in either state, however, the LOW-to-HIGH \bar{CE} transition must occur only when the clock is HIGH. Also, the \bar{U}/D input should be changed only when either \bar{CE} or CP is HIGH. Overflow/underflow indications are provided by two types of outputs, the terminal count (TC) and ripple clock (\bar{RC}). The TC output is normally LOW and goes HIGH when a circuit reaches zero in the count-down mode or reaches "9" in the count-up-mode. The TC output will remain HIGH until a state change occurs, either by counting or presetting, or until \bar{U}/D is changed. Do not use the TC output as a clock signal because it is subject to decoding spikes. The TC signal is used internally to enable the \bar{RC} output. When TC is HIGH and \bar{CE} is LOW, the \bar{RC} output follows the clock pulse (CP). This feature simplifies the design of multistage counters as shown in Figure 5 and 6.

In Figure 5, each \bar{RC} output is used as the clock input to the next higher stage. It is only necessary to inhibit the first stage to prevent counting in all stages, since a HIGH on CE inhibits the RC output pulse as indicated in the function table. The timing skew between state changes in the first and last stages is represented by the cumulative delay of the clock as it ripples through the preceding stages. This can be a disadvantage of this configuration in some applications.

Figure 6 shows a method of causing state changes to occur simultaneously in all stages. The \bar{RC} outputs propagate the carry/borrow signals in ripple fashion and all clock inputs are driven in parallel. In this configuration the duration of the clock LOW state must be long enough to allow the negative-going edge

of the carry/borrow signal to ripple through to the last stage before the clock goes HIGH. Since the \bar{RC} output of any package goes HIGH shortly after its CP input goes HIGH there is no such restriction on the HIGH-state duration of the clock.

In Figure 7, the configuration shown avoids ripple delays and their associated restrictions. Combining the TC signals from all the preceding stages forms the \bar{CE} input for a given stage. An enable must be included in each carry gate in order to inhibit counting. The TC output of a given stage is not affected by its own \bar{CE} signal therefore the simple inhibit scheme of Figure 5 and 6 does not apply.

Features

- Input levels:
For SN74HC190: CMOS level
For SN74HCT190: TTL level
- Synchronous reversible counting
- Asynchronous parallel load
- Count enable control for synchronous expansion



- Single up/down control input
- Specified from -40°C to +125°C
- Packaging information: DIP16/SOP16/TSSOP16

Ordering Information

Product Model	Package Type	Marking	Packing	Packing Qty
XBLW SN74HC190N	DIP-16	74HC190N	Tube	1000Pcs/Box
XBLW SN74HC190DTR	SOP-16	74HC190	Tape	2500Pcs/Reel
XBLW SN74HC190TDTR	TSSOP-16	74HC190	Tape	3000Pcs/Reel
XBLW SN74HCT190N	DIP-16	74HCT190N	Tube	1000Pcs/Box
XBLW SN74HCT190DTR	SOP-16	74HCT190	Tape	2500Pcs/Reel
XBLW SN74HCT190TDTR	TSSOP-16	74HCT190	Tape	3000Pcs/Reel

Block Diagram And Pin Description

Block Diagram

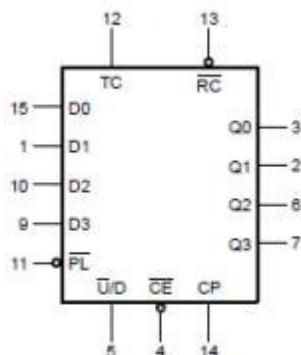


Figure 1. Logic symbol

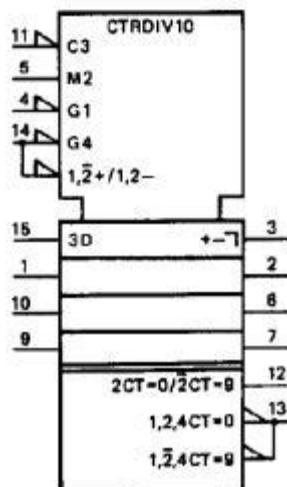


Figure 2. IEC logic symbol

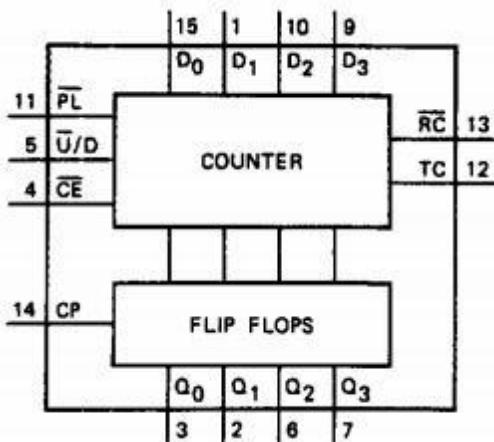


Figure 3. Functional diagram

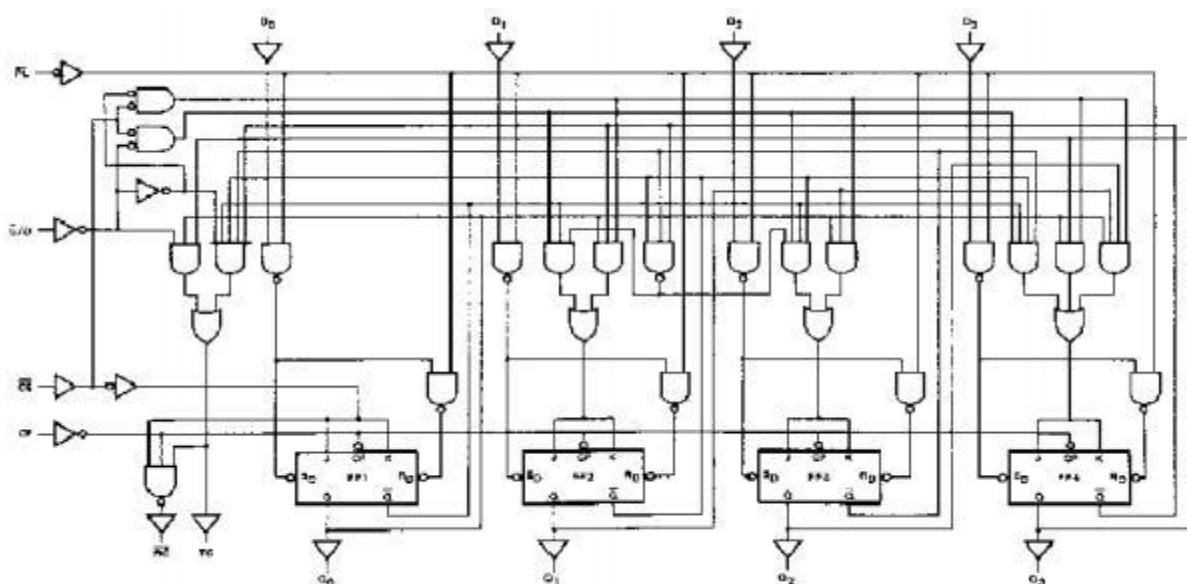


Figure 4. Logic diagram

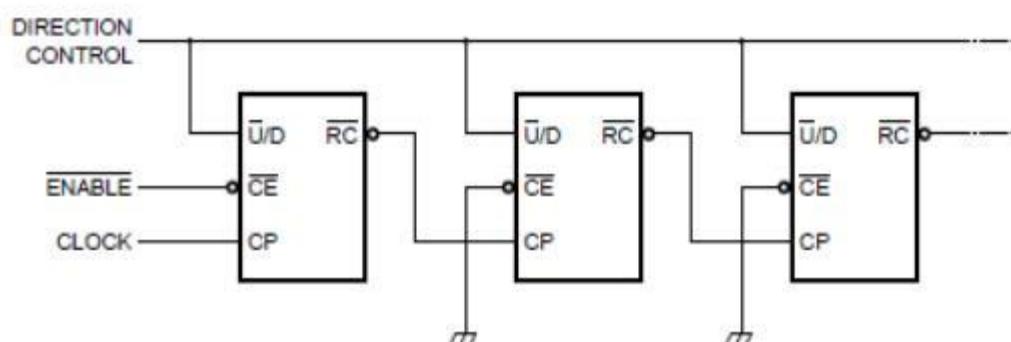


Figure 5. N-stage ripple counter using ripple clock

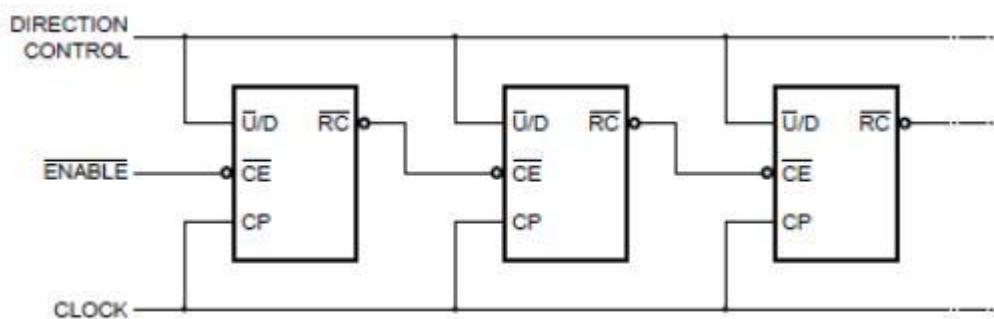


Figure 6. Synchronous n-stage counter using ripple carry/borrow

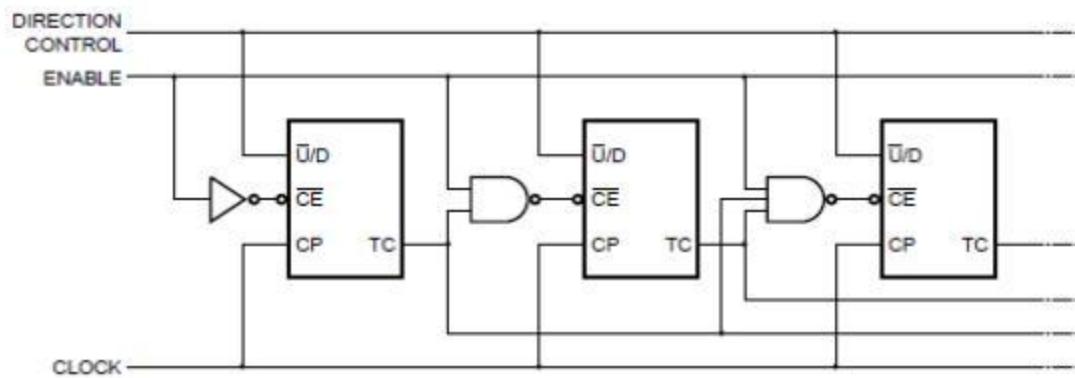


Figure 7. Synchronous n-stage counter with parallel gated carry/borrow

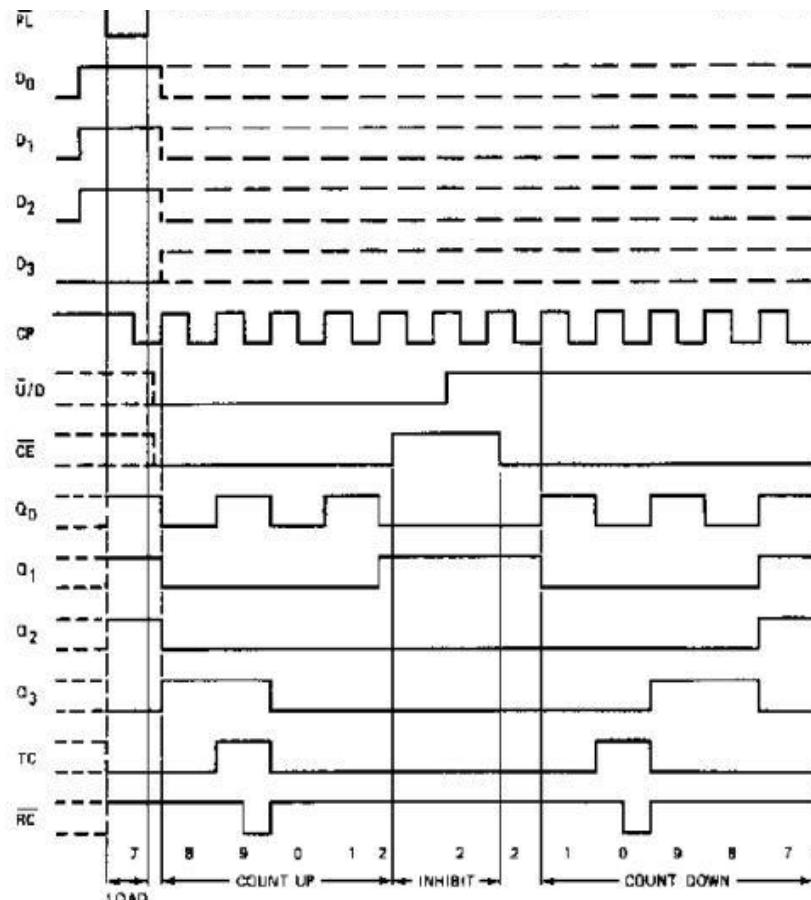
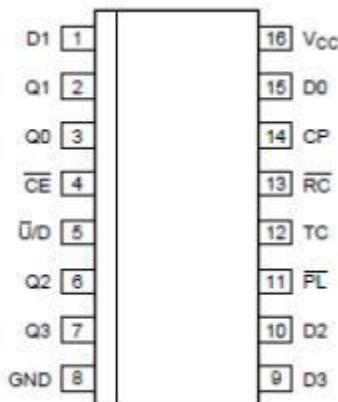


Figure 8. Typical timing sequence



Pin Configurations



Pin Description

Pin No.	Pin Name	Description
1	D1	data input
2	Q1	flip-flop output
3	Q0	flip-flop output
4	CE	count enable input (active LOW)
5	U/D	up/down input
6	Q2	flip-flop output
7	Q3	flip-flop output
8	GND	ground (0V)
9	D3	data input
10	D2	data input
11	PL	parallel load input (active LOW)
12	TC	terminal count output
13	RC	ripple clock output (active LOW)
14	CP	clock input (LOW-to-HIGH, edge-triggered)
15	D0	data input
16	VCC	supply voltage

Function Table

Operating mode	Input					Output
	PL	U/D	CE	CP	Dn	
parallel load	L	X	X	X	L	L
	L	X	X	X	H	H
count up	H	L	I	↑	X	count up
count down	H	H	I	↑	X	count down
hold (do nothing)	H	X	H	X	X	no change

Note: H=HIGH voltage level; L=LOW voltage level; X=don't care; ↑=LOW-to-HIGH clock

I=LOW voltage level one set-up time prior to the LOW-to-HIGH clock transition.



Input			Terminal count state				Output	
\bar{U}/D	\bar{CE}	CP	Q_0	Q_1	Q_2	Q_3	TC	\bar{RC}
H	H	X	H	X	X	H	L	H
L	H	X	H	X	X	H	H	H
L	L		H	X	X	H		
L	H	X	L	L	L	L	L	H
H	H	X	L	L	L	L	H	H
H	L		L	L	L	L		

Note:

[1] H=HIGH voltage level; L=LOW voltage level; X=don't care.

— —

[2] — =one LOW level output pulse.

[3] — =TC goes LOW on a LOW-to-HIGH clock transition.



Electrical Parameter

Absolute Maximum Ratings

(Voltages are referenced to GND(ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions		Min.	Max.	Unit
supply voltage	V _{CC}	-		-0.5	+7.0	V
input clamping current	I _{IK}	V _I < -0.5V or V _I > V _{CC} +0.5V		-	±20	mA
output clamping current	I _{OK}	V _O < -0.5V or V _O > V _{CC} +0.5V		-	±20	mA
output current	I _O	V _O = -0.5V to V _{CC} +0.5V		-	±25	mA
supply current	I _{CC}	-		-	+50	mA
ground current	I _{GND}	-		-50	-	mA
storage temperature	T _{stg}	-		-65	+150	°C
total power dissipation	P _{tot}	-		-	500	mW
Soldering temperature	T _L	10s	DIP SOP/TSSOP	245 260		°C

Recommended Operating Conditions

Parameter	Symbol	Conditions		Min.	Typ.	Max.	Unit
SN74HC190							
supply voltage	V _{CC}	-		2.0	5.0	6.0	V
input voltage	V _I	-		0	-	V _{CC}	V
output voltage	V _O	-		0	-	V _{CC}	V
input transition rise and fall rate	Δt/ΔV	V _{CC} =2.0V		-	-	625	ns/V
		V _{CC} =4.5V		-	1.67	139	ns/V
		V _{CC} =6.0V		-	-	83	ns/V
ambient temperature	T _{amb}	-		-40	-	+125	°C
SN74HCT190							
supply voltage	V _{CC}	-		4.5	5.0	5.5	V
input voltage	V _I	-		0	-	V _{CC}	V
output voltage	V _O	-		0	-	V _{CC}	V
input transition rise and fall rate	Δt/ΔV	V _{CC} =2.0V		-	-	-	ns/V
		V _{CC} =4.5V		-	1.67	139	ns/V
		V _{CC} =6.0V		-	-	-	ns/V
ambient temperature	T _{amb}	-		-40	-	+125	°C



DC Characteristics 1

($T_{amb}=25^{\circ}C$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
SN74HC190							
HIGH-level input voltage	V_{IH}	$V_{CC}=2.0V$	1.5	1.2	-	V	
		$V_{CC}=4.5V$	3.15	2.4	-	V	
		$V_{CC}=6.0V$	4.2	3.2	-	V	
LOW-level input voltage	V_{IL}	$V_{CC}=2.0V$	-	0.8	0.5	V	
		$V_{CC}=4.5V$	-	2.1	1.35	V	
		$V_{CC}=6.0V$	-	2.8	1.8	V	
HIGH-level output voltage	V_{OH}	$V_I = V_{IH}$ or V_{IL}	$I_O=-20\mu A; V_{CC}=2.0V$	1.9	2.0	-	V
			$I_O=-20\mu A; V_{CC}=4.5V$	4.4	4.5	-	V
			$I_O=-20\mu A; V_{CC}=6.0V$	5.9	6.0	-	V
			$I_O=-4.0mA; V_{CC}=4.5V$	3.98	4.32	-	V
			$I_O=-5.2mA; V_{CC}=6.0V$	5.48	5.81	-	V
LOW-level output voltage	V_{OL}	$V_I = V_{IH}$ or V_{IL}	$I_O=20\mu A; V_{CC}=2.0V$	-	0	0.1	V
			$I_O=20\mu A; V_{CC}=4.5V$	-	0	0.1	V
			$I_O=20\mu A; V_{CC}=6.0V$	-	0	0.1	V
			$I_O=4.0mA; V_{CC}=4.5V$	-	0.15	0.26	V
			$I_O=5.2mA; V_{CC}=6.0V$	-	0.16	0.26	V
input leakage current	I_I	$V_I=V_{CC}$ or GND; $V_{CC}=6.0V$	-	-	± 1.0	μA	
supply current	I_{CC}	$V_I=V_{CC}$ or GND; $I_O=0A$; $V_{CC}=6.0V$	-	-	8.0	μA	
input capacitance	C_I	-	-	3.5	-	pF	
SN74HCT190							
HIGH-level input voltage	V_{IH}	$V_{CC}=4.5V$ to 5.5V	2.0	1.6	-	V	
LOW-level input voltage	V_{IL}	$V_{CC}=4.5V$ to 5.5V	-	1.2	0.8	V	
HIGH-level output voltage	V_{OH}	$V_I = V_{IH}$ or V_{IL} ; $V_{CC}=4.5V$	$I_O=-20\mu A$	4.4	4.5	-	V
			$I_O=-4.0mA$	3.98	4.32	-	V
LOW-level output voltage	V_{OL}	$V_I = V_{IH}$ or V_{IL} ; $V_{CC}=4.5V$	$I_O=20\mu A$	-	0	0.1	V
			$I_O=4.0mA$	-	0.16	0.26	V
input leakage current	I_I	$V_I=V_{CC}$ or GND; $V_{CC}=5.5V$	-	-	± 1.0	μA	
supply current	I_{CC}	$V_I=V_{CC}$ or GND; $I_O=0A$; $V_{CC}=5.5V$	-	-	8.0	μA	
additional supply current	ΔI_{CC}	$V_I=V_{CC}-2.1V$; other inputs at V_{CC} or GND; $I_O=0A$; $V_{CC}=4.5V$ to 5.5V	-	-	360	μA	
input capacitance	C_I	-	-	3.5	-	pF	



DC Characteristics 2

(T_{amb} =-40°C to +85°C, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
SN74HC190							
HIGH-level input voltage	V_{IH}	$V_{CC}=2.0V$	1.5	-	-	V	
		$V_{CC}=4.5V$	3.15	-	-	V	
		$V_{CC}=6.0V$	4.2	-	-	V	
LOW-level input voltage	V_{IL}	$V_{CC}=2.0V$	-	-	0.5	V	
		$V_{CC}=4.5V$	-	-	1.35	V	
		$V_{CC}=6.0V$	-	-	1.8	V	
HIGH-level output voltage	V_{OH}	$V_I = V_{IH}$ or V_{IL}	$I_O=-20\mu A; V_{CC}=2.0V$	1.9	-	V	
			$I_O=-20\mu A; V_{CC}=4.5V$	4.4	-	V	
			$I_O=-20\mu A; V_{CC}=6.0V$	5.9	-	V	
			$I_O=-4.0mA; V_{CC}=4.5V$	3.84	-	V	
			$I_O=-5.2mA; V_{CC}=6.0V$	5.34	-	V	
LOW-level output voltage	V_{OL}	$V_I = V_{IH}$ or V_{IL}	$I_O=20\mu A; V_{CC}=2.0V$	-	-	0.1	V
			$I_O=20\mu A; V_{CC}=4.5V$	-	-	0.1	V
			$I_O=20\mu A; V_{CC}=6.0V$	-	-	0.1	V
			$I_O=4.0mA; V_{CC}=4.5V$	-	-	0.33	V
			$I_O=5.2mA; V_{CC}=6.0V$	-	-	0.33	V
input leakage current	I_I	$V_I=V_{CC}$ or GND; $V_{CC}=6.0V$	-	-	± 1.0	μA	
supply current	I_{CC}	$V_I=V_{CC}$ or GND; $I_O=0A$; $V_{CC}=6.0V$	-	-	80	μA	
SN74HCT190							
HIGH-level input voltage	V_{IH}	$V_{CC}=4.5V$ to 5.5V	2.0	-	-	V	
LOW-level input voltage	V_{IL}	$V_{CC}=4.5V$ to 5.5V	-	-	0.8	V	

HIGH-level output voltage	V_{OH}	$V_I = V_{IH}$ or V_{IL} ; $V_{CC}=4.5V$	$I_O=-20\mu A$	4.4	-	-	V
			$I_O=-4.0mA$	3.84	-	-	V
LOW-level output voltage	V_{OL}	$V_I = V_{IH}$ or V_{IL} ; $V_{CC}=4.5V$	$I_O=20\mu A$	-	-	0.1	V
			$I_O=4.0mA$	-	-	0.33	V
input leakage current	I_I	$V_I=V_{CC}$ or GND; $V_{CC}=5.5V$	-	-	± 1.0	μA	
supply current	I_{CC}	$V_I=V_{CC}$ or GND; $I_O=0A$; $V_{CC}=5.5V$	-	-	80	μA	
additional supply current	ΔI_{CC}	$V_I=V_{CC}-2.1V$; other inputs at V_{CC} or GND; $I_O=0A$; $V_{CC}=4.5V$ to 5.5V	-	-	450	μA	



DC Characteristics 3

($T_{amb} = -40^{\circ}\text{C}$ to $+125^{\circ}\text{C}$, voltages are referenced to GND (ground=0V), unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
SN74HC190							
HIGH-level input voltage	V_{IH}	$V_{CC}=2.0\text{V}$	1.5	-	-	V	
		$V_{CC}=4.5\text{V}$	3.15	-	-	V	
		$V_{CC}=6.0\text{V}$	4.2	-	-	V	
LOW-level input voltage	V_{IL}	$V_{CC}=2.0\text{V}$	-	-	0.5	V	
		$V_{CC}=4.5\text{V}$	-	-	1.35	V	
		$V_{CC}=6.0\text{V}$	-	-	1.8	V	
HIGH-level output voltage	V_{OH}	$V_I = V_{IH}$ or V_{IL}	$I_O=-20\mu\text{A}; V_{CC}=2.0\text{V}$	1.9	-	V	
			$I_O=-20\mu\text{A}; V_{CC}=4.5\text{V}$	4.4	-	V	
			$I_O=-20\mu\text{A}; V_{CC}=6.0\text{V}$	5.9	-	V	
			$I_O=-4.0\text{mA}; V_{CC}=4.5\text{V}$	3.7	-	V	
			$I_O=-5.2\text{mA}; V_{CC}=6.0\text{V}$	5.2	-	V	
LOW-level output voltage	V_{OL}	$V_I = V_{IH}$ or V_{IL}	$I_O=20\mu\text{A}; V_{CC}=2.0\text{V}$	-	-	0.1	V
			$I_O=20\mu\text{A}; V_{CC}=4.5\text{V}$	-	-	0.1	V
			$I_O=20\mu\text{A}; V_{CC}=6.0\text{V}$	-	-	0.1	V
			$I_O=4.0\text{mA}; V_{CC}=4.5\text{V}$	-	-	0.4	V
			$I_O=5.2\text{mA}; V_{CC}=6.0\text{V}$	-	-	0.4	V
input leakage current	I_I	$V_I=V_{CC}$ or GND; $V_{CC}=6.0\text{V}$	-	-	± 1.0	uA	
supply current	I_{CC}	$V_I=V_{CC}$ or GND; $I_O=0\text{A}$; $V_{CC}=6.0\text{V}$	-	-	160	uA	
SN74HCT190							
HIGH-level input voltage	V_{IH}	$V_{CC}=4.5\text{V}$ to 5.5V	2.0	-	-	V	
LOW-level input voltage	V_{IL}	$V_{CC}=4.5\text{V}$ to 5.5V	-	-	0.8	V	
HIGH-level output voltage	V_{OH}	$V_I = V_{IH}$ or V_{IL} ; $V_{CC}=4.5\text{V}$	$I_O=-20\mu\text{A}$	4.4	-	V	
			$I_O=-4.0\text{mA}$	3.7	-	V	
LOW-level output voltage	V_{OL}	$V_I = V_{IH}$ or V_{IL} ; $V_{CC}=4.5\text{V}$	$I_O=20\mu\text{A}$	-	-	0.1	V
			$I_O=4.0\text{mA}$	-	-	0.4	V
input leakage current	I_I	$V_I=V_{CC}$ or GND; $V_{CC}=5.5\text{V}$	-	-	± 1.0	uA	
supply current	I_{CC}	$V_I=V_{CC}$ or GND; $I_O=0\text{A}$; $V_{CC}=5.5\text{V}$	-	-	160	uA	
additional	ΔI_{CC}	$V_I=V_{CC}-2.1\text{V}$;	-	-	490	uA	
supply current		other inputs at V_{CC} or GND; $I_O=0\text{A}$; $V_{CC}=4.5\text{V}$ to 5.5V					



AC Characteristics 1

($T_{amb}=25^{\circ}C$, GND=0V; $t_r=t_f=6\text{ns}$; $C_L=50\text{pF}$, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit	
SN74HC190							
propagation delay	t_{pd}	CP to Qn; see Figure 10	$V_{CC}=2.0\text{V}$	-	72	220	ns
			$V_{CC}=4.5\text{V}$	-	26	44	ns
			$V_{CC}=5.0\text{V}; C_L=15\text{pF}$	-	22	-	ns
			$V_{CC}=6.0\text{V}$	-	21	37	ns
		CP to TC; see Figure 10	$V_{CC}=2.0\text{V}$	-	83	255	ns
			$V_{CC}=4.5\text{V}$	-	30	51	ns
			$V_{CC}=6.0\text{V}$	-	24	43	ns
		CP to \bar{RC} ; see Figure 11	$V_{CC}=2.0\text{V}$	-	44	150	ns
			$V_{CC}=4.5\text{V}$	-	16	30	ns
			$V_{CC}=6.0\text{V}$	-	13	26	ns
		\bar{CE} to \bar{RC} ; see Figure 11	$V_{CC}=2.0\text{V}$	-	33	130	ns
			$V_{CC}=4.5\text{V}$	-	12	26	ns
			$V_{CC}=6.0\text{V}$	-	10	22	ns
		Dn to Qn; see Figure 12	$V_{CC}=2.0\text{V}$	-	63	220	ns
			$V_{CC}=4.5\text{V}$	-	23	44	ns
			$V_{CC}=6.0\text{V}$	-	18	37	ns
		\bar{PL} to Qn; see Figure 13	$V_{CC}=2.0\text{V}$	-	63	220	ns
			$V_{CC}=4.5\text{V}$	-	23	44	ns
			$V_{CC}=6.0\text{V}$	-	18	37	ns
		$\bar{U/D}$ to TC; see Figure 14	$V_{CC}=2.0\text{V}$	-	44	190	ns
			$V_{CC}=4.5\text{V}$	-	16	38	ns
			$V_{CC}=6.0\text{V}$	-	13	32	ns
		$\bar{U/D}$ to \bar{RC} ; see Figure 14	$V_{CC}=2.0\text{V}$	-	50	210	ns
			$V_{CC}=4.5\text{V}$	-	18	42	ns
			$V_{CC}=6.0\text{V}$	-	14	36	ns
transition time	t_t	see Figure 15	$V_{CC}=2.0\text{V}$	-	19	75	ns
			$V_{CC}=4.5\text{V}$	-	7	15	ns
			$V_{CC}=6.0\text{V}$	-	6	13	ns
pulse width	t_w	CP; HIGH or LOW; see Figure 10	$V_{CC}=2.0\text{V}$	155	28	-	ns
			$V_{CC}=4.5\text{V}$	31	10	-	ns
			$V_{CC}=6.0\text{V}$	26	8	-	ns
		\bar{PL} ; LOW; see Figure 15	$V_{CC}=2.0\text{V}$	100	25	-	ns
			$V_{CC}=4.5\text{V}$	20	9	-	ns
			$V_{CC}=6.0\text{V}$	17	7	-	ns
recovery time	t_{rec}	\bar{PL} to CP; see Figure 15	$V_{CC}=2.0\text{V}$	35	8	-	ns
			$V_{CC}=4.5\text{V}$	7	3	-	ns
			$V_{CC}=6.0\text{V}$	6	2	-	ns
set-up time	t_{su}	$\bar{U/D}$ to CP;	$V_{CC}=2.0\text{V}$	205	61	-	ns



			see Figure 16	V _{CC} =4.5V	41	22	-	ns
				V _{CC} =6.0V	35	18	-	ns
			Dn to \bar{P}_L ; see Figure 17	V _{CC} =2.0V	100	19	-	ns
				V _{CC} =4.5V	20	7	-	ns
				V _{CC} =6.0V	17	6	-	ns
				V _{CC} =2.0V	140	39	-	ns
				V _{CC} =4.5V	28	14	-	ns
				V _{CC} =6.0V	24	11	-	ns
			\bar{U}/D to CP; see Figure 16	V _{CC} =2.0V	0	-44	-	ns
				V _{CC} =4.5V	0	-16	-	ns
				V _{CC} =6.0V	0	-13	-	ns
hold time	t_h	\bar{U}/D to CP; see Figure 16	V _{CC} =2.0V	0	-14	-	ns	
			V _{CC} =4.5V	0	-5	-	ns	
			V _{CC} =6.0V	0	-4	-	ns	
		Dn to \bar{P}_L ; see Figure 17	V _{CC} =2.0V	0	-19	-	ns	
			V _{CC} =4.5V	0	-7	-	ns	
			V _{CC} =6.0V	0	-6	-	ns	
		CP; see Figure 10	V _{CC} =2.0V	3.0	8.3	-	MHz	
			V _{CC} =4.5V	15	25	-	MHz	
			V _{CC} =5.0V; C _L =15pF	-	28	-	MHz	
			V _{CC} =6.0V	18	30	-	MHz	
power dissipation capacitance	C _{PD}	V _I =GND to V _{CC}			-	36	-	pF
SN74HCT190								
propagation delay	t_{pd}	CP to Q _n ; see Figure 10	V _{CC} =4.5V	-	28	48	ns	
			V _{CC} =5.0V; C _L =15pF	-	24	-	ns	
		CP to T _C ; see Figure 10	V _{CC} =4.5V	-	34	58	ns	
			V _{CC} =4.5V	-	20	35	ns	
		$\bar{C}E$ to $\bar{R}C$; see Figure 11	V _{CC} =4.5V	-	18	33	ns	
			V _{CC} =4.5V	-	24	44	ns	
		Dn to Q _n ; see Figure 12	V _{CC} =4.5V	-	29	49	ns	
			V _{CC} =4.5V	-	24	45	ns	
		$\bar{P}L$ to Q _n ; see Figure 13	V _{CC} =4.5V	-	26	45	ns	
			V _{CC} =4.5V	-	24	45	ns	
		\bar{U}/D to T _C ; see Figure 14	V _{CC} =4.5V	-	26	45	ns	
			V _{CC} =4.5V	-	24	45	ns	
transition time	t_t	V _{CC} =4.5V; see Figure 15			-	7	15	ns
pulse width	t_w	CP; HIGH or LOW; V _{CC} =4.5V see Figure 10			25	10	-	ns
		$\bar{P}L$; LOW; V _{CC} =4.5V; see Figure 15			22	12	-	ns
recovery time	t_{rec}	$\bar{P}L$ to CP; V _{CC} =4.5V; see Figure 15			7	1	-	ns



set-up time	t_{su}	\bar{U}/D to CP; $V_{CC}=4.5V$; see Figure 16	42	25	-	ns	
		Dn to \bar{PL} ; $V_{CC}=4.5V$; see Figure 17	20	10	-	ns	
		\bar{CE} to CP; $V_{CC}=4.5V$; see Figure 16	31	18	-	ns	
hold time	t_h	\bar{U}/D to CP; $V_{CC}=4.5V$; see Figure 16	0	-18	-	ns	
		Dn to \bar{PL} ; $V_{CC}=4.5V$; see Figure 17	0	-6	-	ns	
		\bar{CE} to CP; $V_{CC}=4.5V$; see Figure 16	0	-10	-	ns	
maximum frequency	f_{max}	CP; see Figure 10	$V_{CC}=4.5V$	16	27	-	MHz
			$V_{CC}=5.0V$; $C_L=15pF$	-	30	-	MHz
power dissipation capacitance	C_{PD}	$V_I=GND$ to $V_{CC}-1.5V$		-	38	-	pF

Note:

[1] t_{pd} is the same as t_{PLH} and t_{PHL} .

[2] t_i is the same as t_{THL} and t_{TLH} .

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in uW).

$$P_D=C_{PD} \times V_{CC}^2 \times f_i + \Sigma(C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i =input frequency in MHz;

f_o =output frequency in MHz;

C_L =output load capacitance in pF;

V_{CC} =supply voltage in V;

$\Sigma(C_L \times V_{CC}^2 \times f_o)=$ sum of outputs.

AC Characteristics 2

($T_{amb}=-40^\circ C$ to $+85^\circ C$, GND=0V; $t_r=t_f=6ns$; $C_L=50pF$, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
SN74HC190						
propagation delay	t_{pd}	CP to Qn; see Figure 10	$V_{CC}=2.0V$	-	-	275 ns
			$V_{CC}=4.5V$	-	-	55 ns
			$V_{CC}=6.0V$	-	-	47 ns
		CP to TC; see Figure 10	$V_{CC}=2.0V$	-	-	320 ns
			$V_{CC}=4.5V$	-	-	64 ns
			$V_{CC}=6.0V$	-	-	54 ns
		CP to \bar{RC} ; see Figure 11	$V_{CC}=2.0V$	-	-	190 ns
			$V_{CC}=4.5V$	-	-	38 ns
			$V_{CC}=6.0V$	-	-	33 ns
		\bar{CE} to \bar{RC} ; see Figure 11	$V_{CC}=2.0V$	-	-	165 ns
			$V_{CC}=4.5V$	-	-	33 ns
			$V_{CC}=6.0V$	-	-	28 ns
		Dn to Qn; see Figure 12	$V_{CC}=2.0V$	-	-	275 ns
			$V_{CC}=4.5V$	-	-	55 ns
			$V_{CC}=6.0V$	-	-	47 ns
		\bar{PL} to Qn; see Figure 13	$V_{CC}=2.0V$	-	-	275 ns
			$V_{CC}=4.5V$	-	-	55 ns
			$V_{CC}=6.0V$	-	-	47 ns



		U/D to TC; see Figure 14	V _{CC} =2.0V	-	-	240	ns
			V _{CC} =4.5V	-	-	48	ns
			V _{CC} =6.0V	-	-	41	ns
		U/D to RC; see Figure 14	V _{CC} =2.0V	-	-	265	ns
			V _{CC} =4.5V	-	-	53	ns
			V _{CC} =6.0V	-	-	45	ns
transition time	t _t	see Figure 15	V _{CC} =2.0V	-	-	95	ns
			V _{CC} =4.5V	-	-	19	ns
			V _{CC} =6.0V	-	-	16	ns
pulse width	t _w	CP; HIGH or LOW; see Figure 10	V _{CC} =2.0V	195	-	-	ns
			V _{CC} =4.5V	39	-	-	ns
			V _{CC} =6.0V	33	-	-	ns
		PL; LOW; see Figure 15	V _{CC} =2.0V	125	-	-	ns
			V _{CC} =4.5V	25	-	-	ns
			V _{CC} =6.0V	21	-	-	ns
recovery time	t _{rec}	PL to CP; see Figure 15	V _{CC} =2.0V	45	-	-	ns
			V _{CC} =4.5V	9	-	-	ns
			V _{CC} =6.0V	8	-	-	ns
set-up time	t _{su}	U/D to CP; see Figure 16	V _{CC} =2.0V	255	-	-	ns
			V _{CC} =4.5V	51	-	-	ns
			V _{CC} =6.0V	43	-	-	ns
		Dn to PL; see Figure 17	V _{CC} =2.0V	125	-	-	ns
			V _{CC} =4.5V	25	-	-	ns
			V _{CC} =6.0V	21	-	-	ns
		CE to CP; see Figure 16	V _{CC} =2.0V	175	-	-	ns
			V _{CC} =4.5V	35	-	-	ns
			V _{CC} =6.0V	30	-	-	ns
hold time	t _h	U/D to CP; see Figure 16	V _{CC} =2.0V	0	-	-	ns
			V _{CC} =4.5V	0	-	-	ns
			V _{CC} =6.0V	0	-	-	ns
		Dn to PL; see Figure 17	V _{CC} =2.0V	0	-	-	ns
			V _{CC} =4.5V	0	-	-	ns
			V _{CC} =6.0V	0	-	-	ns
		CE to CP; see Figure 16	V _{CC} =2.0V	0	-	-	ns
			V _{CC} =4.5V	0	-	-	ns
			V _{CC} =6.0V	0	-	-	ns
maximum frequency	f _{max}	CP; see Figure 10	V _{CC} =2.0V	2.4	-	-	MHz
			V _{CC} =4.5V	12	-	-	MHz
			V _{CC} =6.0V	14	-	-	MHz
SN74HCT190							
propagation delay	t _{pd}	CP to Qn; see Figure 10	V _{CC} =4.5V	-	-	60	ns
		CP to TC; see Figure 10	V _{CC} =4.5V	-	-	73	ns
		CP to RC; see Figure 11	V _{CC} =4.5V	-	-	44	ns



		CE to RC; see Figure 11	V _{CC} =4.5V	-	-	41	ns
		Dn to Qn; see Figure 12	V _{CC} =4.5V	-	-	55	ns
		PL to Qn; see Figure 13	V _{CC} =4.5V	-	-	61	ns
		U/D to TC; see Figure 14	V _{CC} =4.5V	-	-	56	ns
		U/D to RC; see Figure 14	V _{CC} =4.5V	-	-	56	ns
transition time	t _t	V _{CC} =4.5V; see Figure 15		-	-	19	ns
pulse width	t _w	CP; HIGH or LOW; V _{CC} =4.5V; see Figure 10		31	-	-	ns
		PL; LOW; V _{CC} =4.5V; see Figure 15		28	-	-	ns
recovery time	t _{rec}	PL to CP; V _{CC} =4.5V; see Figure 15		9	-	-	ns
set-up time	t _{su}	U/D to CP; V _{CC} =4.5V; see Figure 16		53	-	-	ns
		Dn to PL; V _{CC} =4.5V; see Figure 17		25	-	-	ns
		CE to CP; V _{CC} =4.5V; see Figure 16		39	-	-	ns
hold time	t _h	U/D to CP; V _{CC} =4.5V; see Figure 16		0	-	-	ns
		Dn to PL; V _{CC} =4.5V; see Figure 17		0	-	-	ns
		CE to CP; V _{CC} =4.5V; see Figure 16		0	-	-	ns
maximum frequency	f _{max}	CP; see Figure 10	V _{CC} =4.5V	13	-	-	MHz

Note:

[1] t_{pd} is the same as t_{PLH} and t_{PHL}.

[2] t_t is the same as t_{THL} and t_{TLH}.

AC Characteristics 3

(T_{amb}=-40°C to +125°C, GND=0V; t_r=t_f=6ns; C_L=50pF, unless otherwise specified.)

Parameter	Symbol	Conditions	Min.	Typ.	Max.	Unit
SN74HC190						
propagation delay	t _{pd}	CP to Qn; see Figure 10	V _{CC} =2.0V	-	-	330 ns
			V _{CC} =4.5V	-	-	66 ns
			V _{CC} =6.0V	-	-	56 ns
		CP to TC; see Figure 10	V _{CC} =2.0V	-	-	384 ns
			V _{CC} =4.5V	-	-	77 ns
			V _{CC} =6.0V	-	-	65 ns
		CP to RC; see Figure 11	V _{CC} =2.0V	-	-	228 ns
			V _{CC} =4.5V	-	-	46 ns
			V _{CC} =6.0V	-	-	40 ns
		CE to RC; see Figure 11	V _{CC} =2.0V	-	-	198 ns
			V _{CC} =4.5V	-	-	40 ns
			V _{CC} =6.0V	-	-	34 ns
		Dn to Qn; see Figure 12	V _{CC} =2.0V	-	-	330 ns
			V _{CC} =4.5V	-	-	66 ns



			V _{CC} =6.0V	-	-	56	ns
\bar{PL} to Qn; see Figure 13			V _{CC} =2.0V	-	-	330	ns
			V _{CC} =4.5V	-	-	66	ns
			V _{CC} =6.0V	-	-	56	ns
			V _{CC} =2.0V	-	-	288	ns
$\bar{U/D}$ to TC; see Figure 14			V _{CC} =4.5V	-	-	58	ns
			V _{CC} =6.0V	-	-	49	ns
			V _{CC} =2.0V	-	-	318	ns
$\bar{U/D}$ to \bar{RC} ; see Figure 14			V _{CC} =4.5V	-	-	64	ns
			V _{CC} =6.0V	-	-	54	ns
			V _{CC} =2.0V	-	-	114	ns
transition time	t_t	see Figure 15	V _{CC} =4.5V	-	-	23	ns
			V _{CC} =6.0V	-	-	19	ns
			CP; HIGH or LOW; see Figure 10	V _{CC} =2.0V	234	-	-
	t_w		V _{CC} =4.5V	47	-	-	ns
			V _{CC} =6.0V	40	-	-	ns
			\bar{PL} ; LOW; see Figure 15	V _{CC} =2.0V	150	-	-
	t_{rec}	\bar{PL} to CP; see Figure 15	V _{CC} =4.5V	30	-	-	ns
			V _{CC} =6.0V	25	-	-	ns
			V _{CC} =2.0V	54	-	-	ns
	t_{su}	$\bar{U/D}$ to CP; see Figure 16	V _{CC} =4.5V	11	-	-	ns
			V _{CC} =6.0V	10	-	-	ns
			V _{CC} =2.0V	306	-	-	ns
	t_{su}	Dn to \bar{PL} ; see Figure 17	V _{CC} =4.5V	61	-	-	ns
			V _{CC} =6.0V	52	-	-	ns
			V _{CC} =2.0V	150	-	-	ns
	t_h	\bar{CE} to CP; see Figure 16	V _{CC} =4.5V	30	-	-	ns
			V _{CC} =6.0V	25	-	-	ns
			V _{CC} =2.0V	210	-	-	ns
	t_h		V _{CC} =4.5V	42	-	-	ns
			V _{CC} =6.0V	36	-	-	ns
			V _{CC} =2.0V	0	-	-	ns
	t_h	$\bar{U/D}$ to CP; see Figure 16	V _{CC} =4.5V	0	-	-	ns
			V _{CC} =6.0V	0	-	-	ns
			V _{CC} =2.0V	0	-	-	ns
	t_h	Dn to \bar{PL} ; see Figure 17	V _{CC} =4.5V	0	-	-	ns
			V _{CC} =6.0V	0	-	-	ns
			V _{CC} =2.0V	0	-	-	ns
	t_h	\bar{CE} to CP; see Figure 16	V _{CC} =4.5V	0	-	-	ns
			V _{CC} =6.0V	0	-	-	ns
			V _{CC} =2.0V	0	-	-	ns
maximum frequency	f_{max}	CP; see Figure 10	V _{CC} =2.0V	2	-	-	MHz
			V _{CC} =4.5V	10	-	-	MHz
			V _{CC} =6.0V	12	-	-	MHz
SN74HCT190							
propagation	t_{pd}	CP to Qn;	V _{CC} =4.5V	-	-	72	ns



delay		see Figure 10					
		CP to TC; see Figure 10	V _{CC} =4.5V	-	-	88	ns
		CP to $\bar{R}C$; see Figure 11	V _{CC} =4.5V	-	-	53	ns
		$\bar{C}E$ to $\bar{R}C$; see Figure 11	V _{CC} =4.5V	-	-	49	ns
		D _n to Q _n ; see Figure 12	V _{CC} =4.5V	-	-	66	ns
		$\bar{P}L$ to Q _n ; see Figure 13	V _{CC} =4.5V	-	-	73	ns
		\bar{U}/D to TC; see Figure 14	V _{CC} =4.5V	-	-	67	ns
		\bar{U}/D to $\bar{R}C$; see Figure 14	V _{CC} =4.5V	-	-	67	ns
transition time	t _t	V _{CC} =4.5V; see Figure 15		-	-	23	ns
pulse width	t _w	CP; HIGH or LOW; V _{CC} =4.5V see Figure 10		37	-	-	ns
		$\bar{P}L$; LOW; V _{CC} =4.5V; see Figure 15		34	-	-	ns
recovery time	t _{rec}	$\bar{P}L$ to CP; V _{CC} =4.5V; see Figure 15		11	-	-	ns
set-up time	t _{su}	\bar{U}/D to CP; V _{CC} =4.5V; see Figure 16		64	-	-	ns
		D _n to $\bar{P}L$; V _{CC} =4.5V; see Figure 17		30	-	-	ns
		$\bar{C}E$ to CP; V _{CC} =4.5V; see Figure 16		47	-	-	ns
hold time	t _h	\bar{U}/D to CP; V _{CC} =4.5V; see Figure 16		0	-	-	ns
		D _n to $\bar{P}L$; V _{CC} =4.5V; see Figure 17		0	-	-	ns
		$\bar{C}E$ to CP; V _{CC} =4.5V; see Figure 16		0	-	-	ns
maximum frequency	f _{max}	CP; see Figure 10	V _{CC} =4.5V	11	-	-	MHz

Note:

[1] t_{pd} is the same as t_{PLH} and t_{PHL}.

[2] t_t is the same as t_{THL} and t_{TLH}.

Testing Circuit

AC Testing Circuit

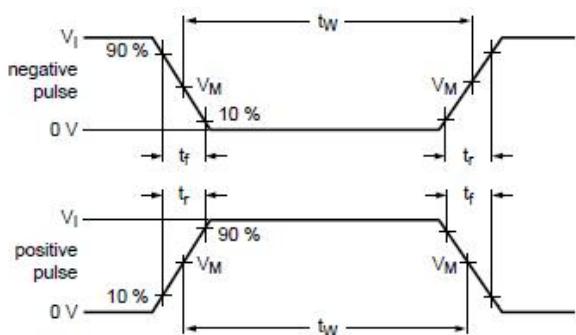


Figure 9. Test circuit for measuring switching times

Definitions for test circuit:

C_L =Load capacitance including jig and probe capacitance.

R_T =Termination resistance should be equal to the output impedance Z_o of the pulse generator.

R_L =Load resistance.

S_1 =Test selection switch

AC Testing Waveforms

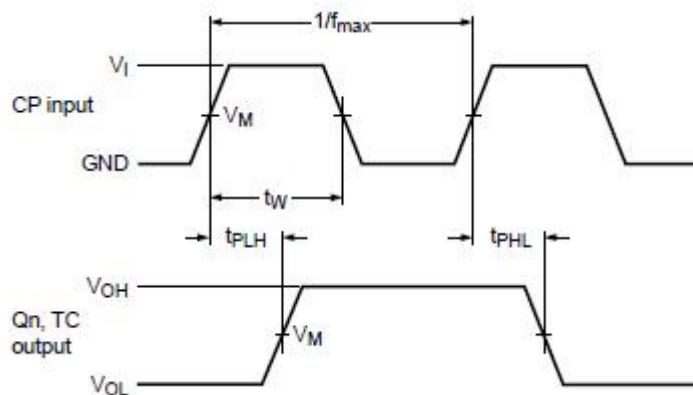


Figure 10. The clock input (CP) to outputs (Qn, TC) propagation delays, clock pulse width and maximum clock frequency

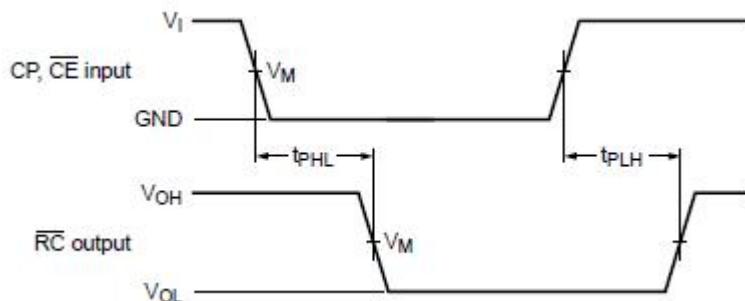


Figure 11. The clock and count enable inputs (CP, CE) to ripple clock output (RC) propagation delays

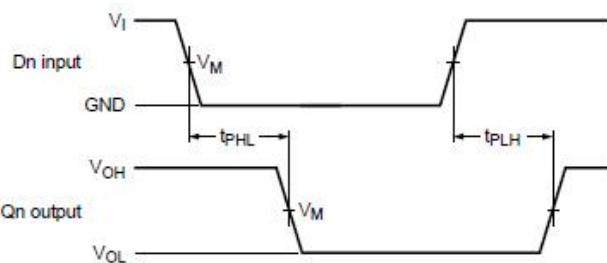


Figure 12. The input (Dn) to output (Qn) propagation delays

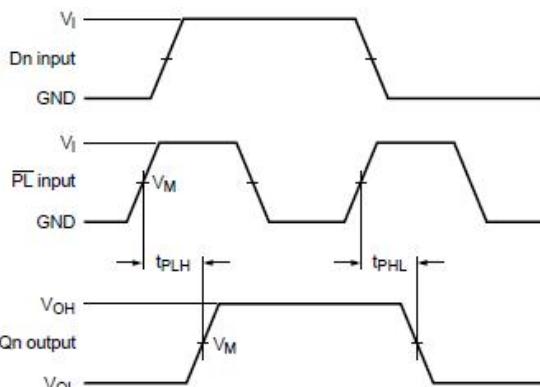


Figure 13. The parallel load input (PL) to output (Qn) propagation delays

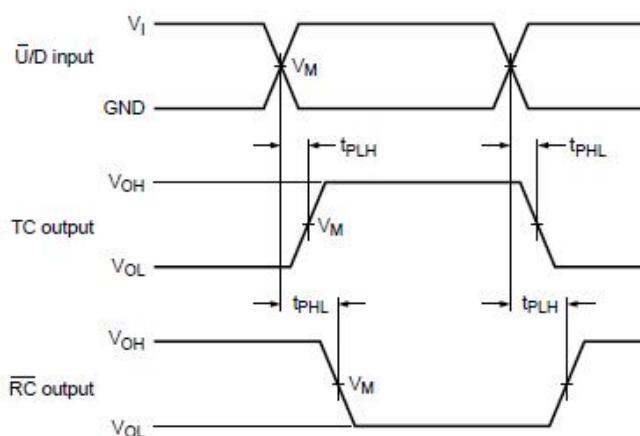


Figure 14. The up/down count input (U/D) to terminal count and ripple clock output (TC, RC) propagation delays

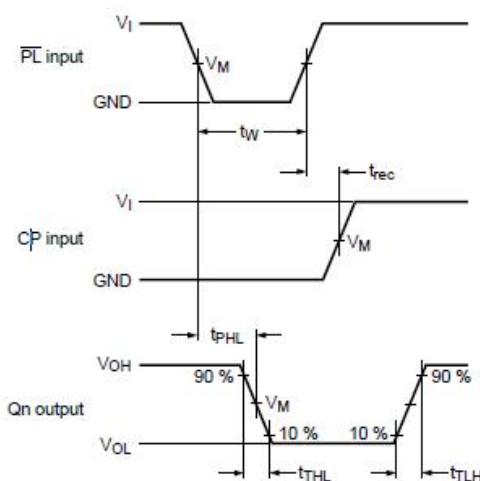


Figure 15. The parallel load input (PL) to clock (CP) recovery times, parallel load pulse width and output (Qn) transition times

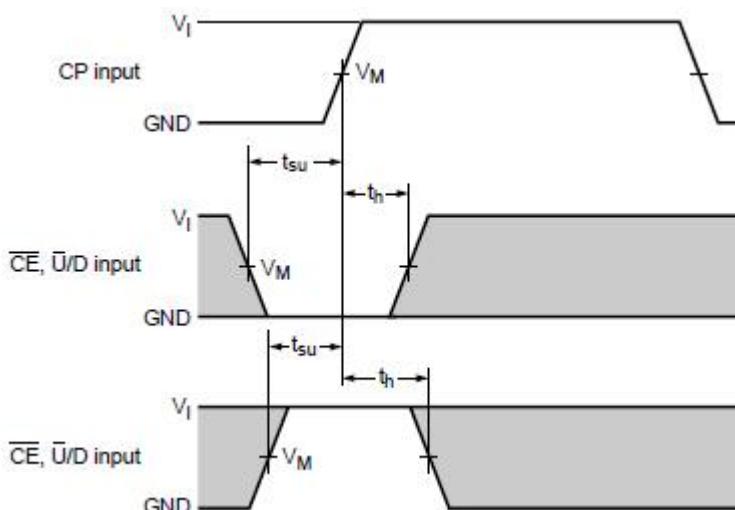


Figure 16. The count enable and up/down count inputs (CE, U/D) to clock input (CP) set-up and hold times

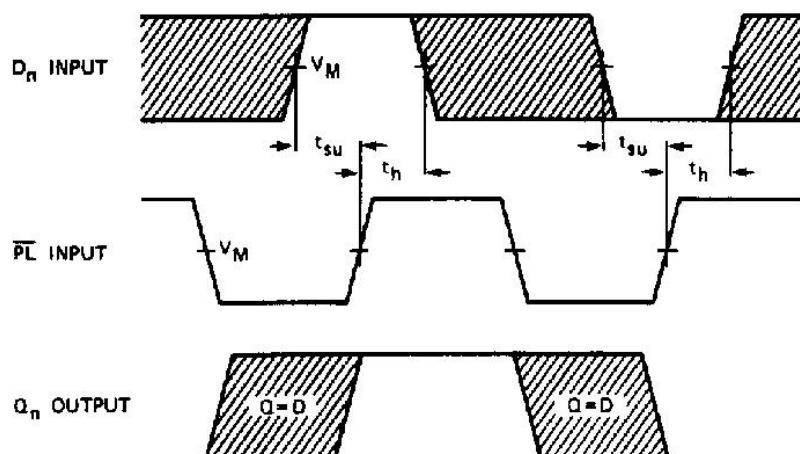


Figure 17. Waveforms showing the set-up and hold times from the parallel load input (PL) to the data input (Dn)

Measurement Points

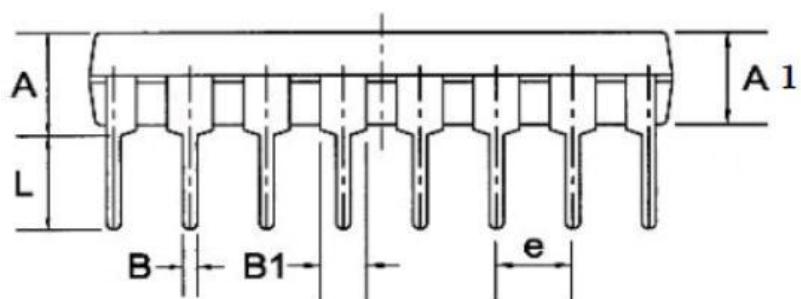
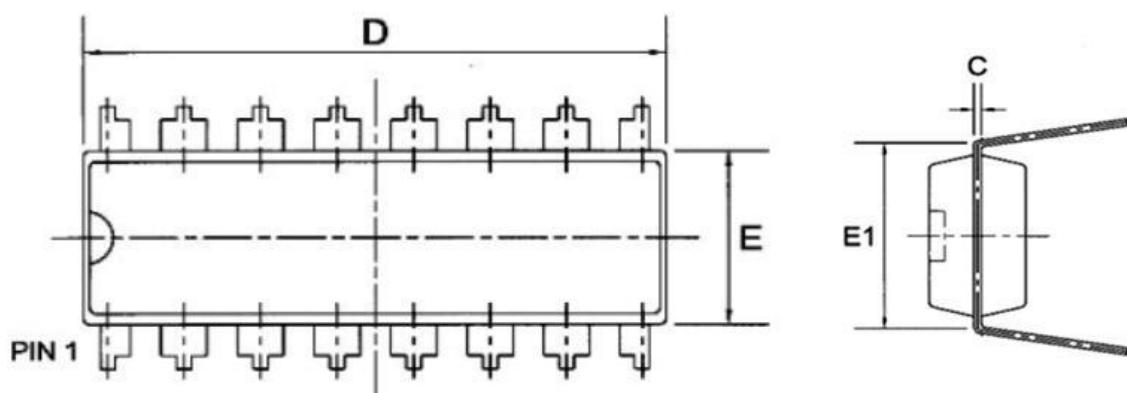
Type	Input		Output	
	V _M		V _M	
SN74HC190	0.5×V _{CC}		0.5×V _{CC}	
SN74HCT190	1.3V		1.3V	

Test Data

Type	Input		Load		S1 position
	V _I	t _r , t _f	C _L	R _L	t _{PLH} , t _{PHL}
SN74HC190	V _{CC}	6ns	15pF, 50pF	1kΩ	open
SN74HCT190	3V	6ns	15pF, 50pF	1kΩ	open

Package Information

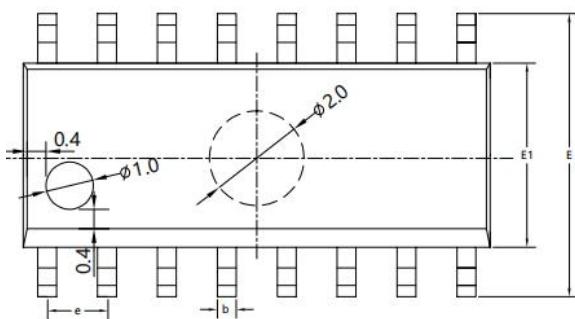
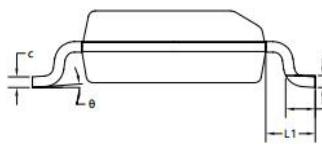
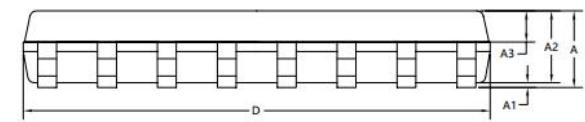
DIP16



Symbol	Dimensions in Millimeters		
	Min	Nom	Max
A	--	--	4.31
A1	3.15	3.30	3.65
B	--	0.50	--
B1	--	1.6	--
C	--	0.27	--
D	19.00	19.20	19.60
E	6.20	6.50	6.60
E1	--	8.0	--
e	--	2.3	--
L	3.00	3.20	3.60



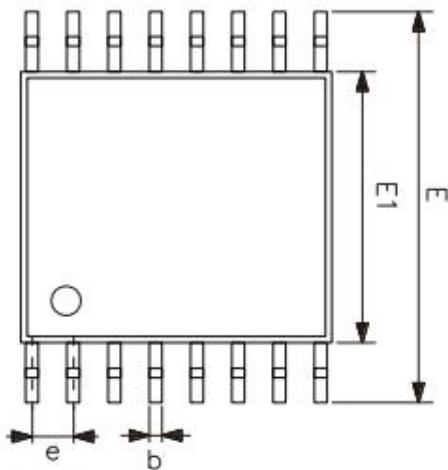
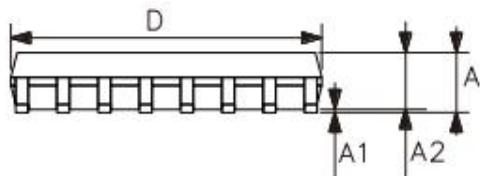
SOP16



SYMBOL	MILIMETER		
	MIN	NOM	MAX
A	1.50	1.60	1.70
A1	0.10	0.15	0.25
A2	1.40	1.45	1.50
A3	0.60	0.65	0.70
b	0.30	0.40	0.50
c	0.15	0.20	0.25
D	9.80	9.90	10.00
E	5.80	6.00	6.20
E1	3.85	3.90	3.95
e	1.27BSC		
L	0.50	0.60	0.70
L1	1.05BSC		
θ	0°	4°	8°



TSSOP16



Symbol	Dimensions (mm)	
	Min.	Max.
A	-	1.20
A1	0.05	0.15
A2	0.80	1.05
b	0.19	0.30
c	0.09	0.20
D	4.90	5.10
E1	4.30	4.50
E	6.20	6.60
e	0.65	
L	0.45	0.75
θ	0°	8°



Statement:

- ✧ Shenzhen xinbole electronics co., ltd. reserves the right to change the product specifications, without notice! Before placing an order, the customer needs to confirm whether the information obtained is the latest version, and verify the integrity of the relevant information.
- ✧ Any semiconductor product is liable to fail or malfunction under certain conditions, and the buyer shall be responsible for complying with safety standards in the system design and whole machine manufacturing using Shenzhen xinbole electronics co., ltd products, and take appropriate security measures to avoid the potential risk of failure may result in personal injury or property losses of the situation occurred!
- ✧ This document is for referenceonly, and the actual use should be based on the application test results.
- ✧ Product performance is never ending, Shenzhen xinbole electronics co., ltd will be dedicated to provide customers with better performance, better quality of integrated circuit products.